

Essentials of MOSFETs

Lecture 5.4: Review of PN Junctions

Short Problem

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Consider a PN diode in which $J_n \gg J_p$ so that the diode current is given by

$$I_D = A_D J_n = q A_D \frac{D_n}{W_P} \frac{n_i^2}{N_A} \left(e^{qV_A/k_B T} - 1 \right).$$

- 1) At a given forward bias at $T = 300$ K, we measure a diode current. How much do we need to increase the forward bias, V_A in order to increase the diode current by a factor of 10?